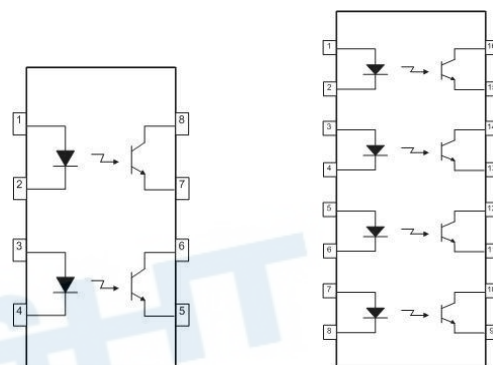


8 PIN 16PIN SSOP PHOTOTRANSISTOR PHOTOCOUPLER ELD3H7(DH)-G, ELQ3H7(DH)-G Series



Schematic



Pin Configuration

Features:

- Compliance Halogens Free
(Br < 900 ppm, Cl < 900 ppm, Br+Cl < 1500 ppm)
- Current transfer ratio
(CTR: 100~600% at IF =5mA, VCE =5V)
- High isolation voltage between input and output
(Viso=3750 V rms)
 - Compact 8 Pin SSOP with a 2.0 mm profile
 - The product itself will remain within RoHS compliant version
 - Compliance with EU REACH
 - UL and cUL approved (No. E214129)
 - VDE approved (No. 40028116)
 - SEMKO approved
 - NEMKO approved
 - DEMKO approved
 - FIMKO approved
 - CQC approved

1, 3 Anode
2, 4 Cathode
5, 7 Emitter
6, 8 Collector

1, 3, 5, 7 Anode
2, 4, 6, 8 Cathode
9, 11, 13, 15 Emitter
10, 12, 14, 16 Collector

Description

The ELD3H7(DH)-G and ELQ3H7(DH)-G contains of an infrared emitting diode optically coupled to a phototransistor detector encapsulated with green compound.

ELD3H7(DH)-G offers 2 channels in a 8-pin small outline SMD package, while ELQ3H7(DH)-G offers 4 channels in a 16-pin small outline SMD package.

Applications

- DC-DC Converters
- Programmable controllers
- Telecommunication equipments
- Signal transmission between circuits of different potentials and impedances

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	60	mA
	Peak forward current (1us, pulse)	I_{FP}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P_D	70	mW
Output	Power dissipation	P_C	150	mW
	Collector current	I_C	50	mA
	Collector-Emitter voltage	V_{CEO}	80	V
	Emitter-Collector voltage	V_{ECO}	7	V
Total Power Dissipation		P_{TOT}	200	mW
Isolation Voltage*1		V_{ISO}	3750	V rms
Operating temperature		T_{OPR}	-55 ~ +110	°C
Storage temperature		T_{STG}	-55 ~ +125	°C
Soldering Temperature*2		T_{SOL}	260	°C

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, LED side pins shorted together, and detector side pins shorted together.

*2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward voltage	V_F	-	1.2	1.4	V	$I_F = 20\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R = 4\text{V}$
Input capacitance	C_{in}	-	30	250	pF	$V = 0, f = 1\text{kHz}$

Output

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	100	nA	$V_{CE} = 20\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_C = 0.1\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	7	-	-	V	$I_E = 0.1\text{mA}$

Transfer Characteristics (Ta=25°C unless specified otherwise)

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Current Transfer ratio	CTR	100	-	400	%	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	0.1	0.2	V	$I_F = 10\text{mA}, I_C = 1\text{mA}$
Isolation resistance	R_{IO}	5×10^{10}	-	-	Ω	$V_{IO} = 500\text{Vdc}$, 40~60% R.H.
Floating capacitance	C_{IO}	-	0.3	1.0	pF	$V_{IO} = 0, f = 1\text{MHz}$
Rise time	t_r	-	5	18	μs	$V_{CE} = 2\text{V}, I_C = 2\text{mA}$, $R_L = 100\Omega$
Fall time	t_f	-	3	18	μs	

* Typical values at $T_a = 25^\circ\text{C}$

Typical Electro-Optical Characteristics Curves

Figure 1. Forward Current vs Forward Voltage

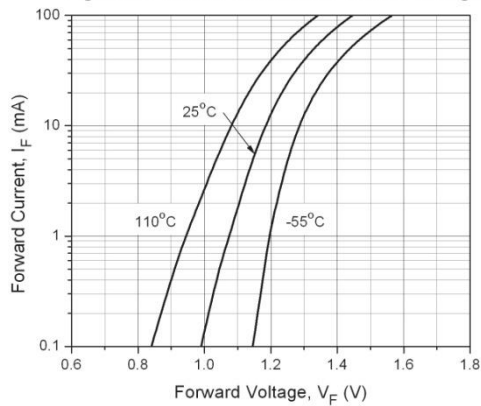


Figure 2. Normalized Collector Current vs Forward Current

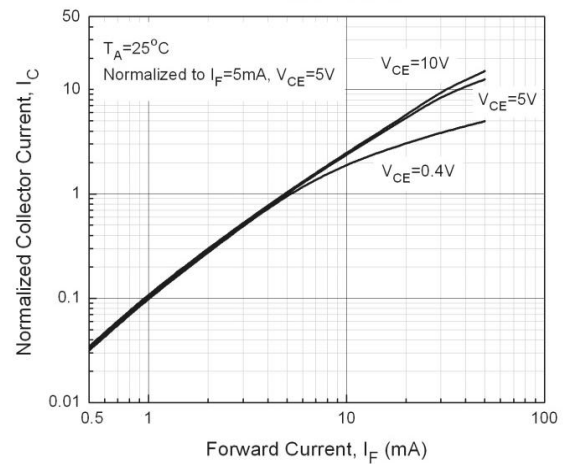


Figure 3. Normalized Current Transfer Ratio vs Forward Current

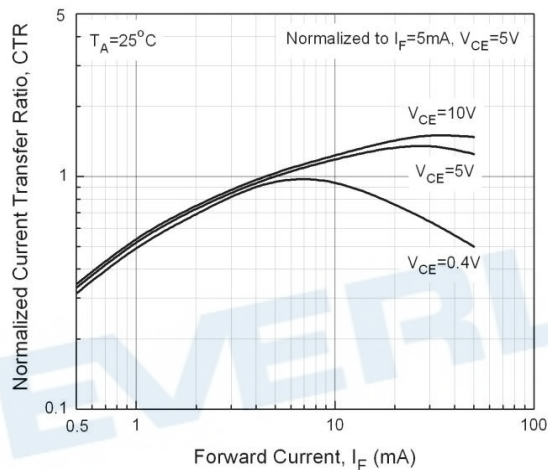


Figure 4. Normalized Collector Current vs Ambient Temperature

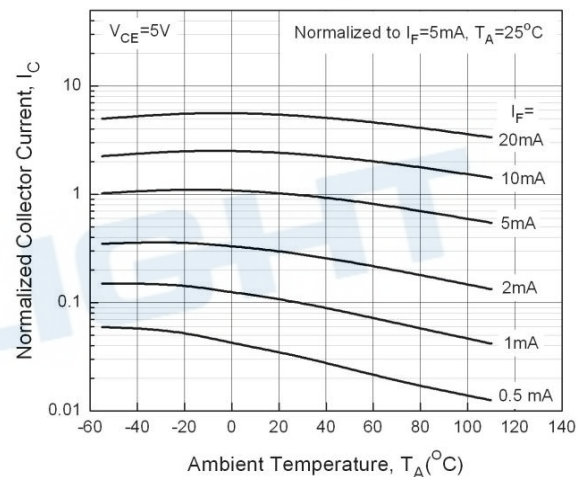


Figure 5. Normalized Current Transfer Ratio vs Ambient Temperature

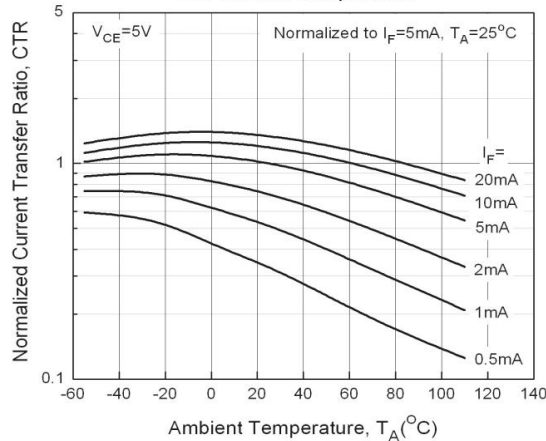


Figure 6. Collector Current vs Collector-Emitter Voltage

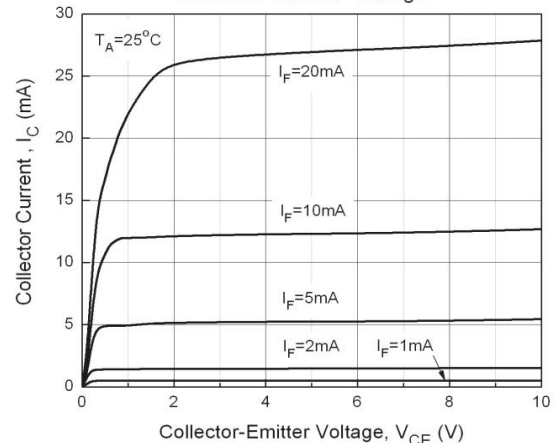


Figure 7. Collector Current vs Collector-Emitter Voltage

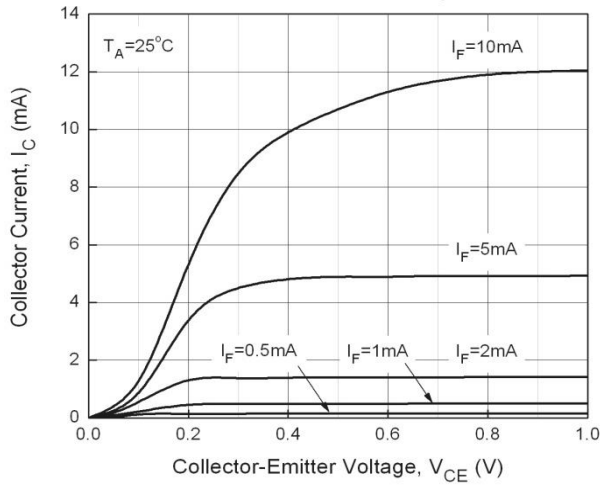


Figure 8. Collector Dark Current vs Ambient Temperature

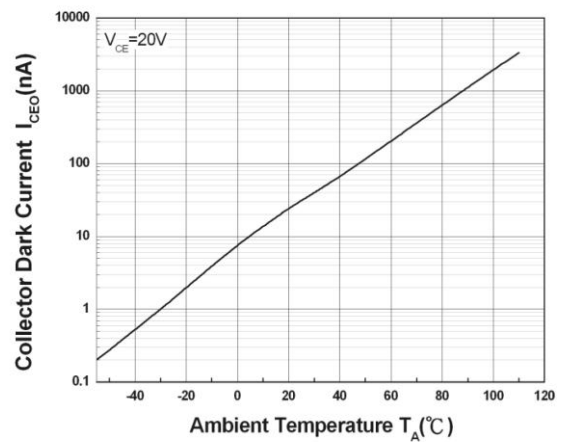


Figure 9. Collector-Emitter Saturation Voltage vs Ambient Temperature

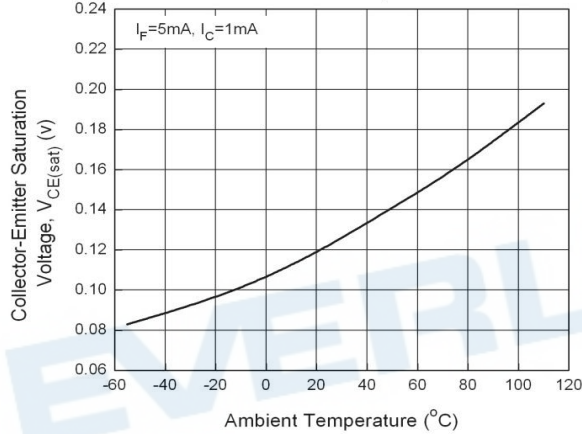


Figure 10. Switching Time vs Load Resistance

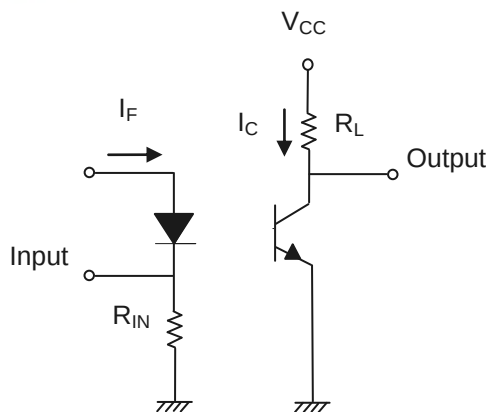
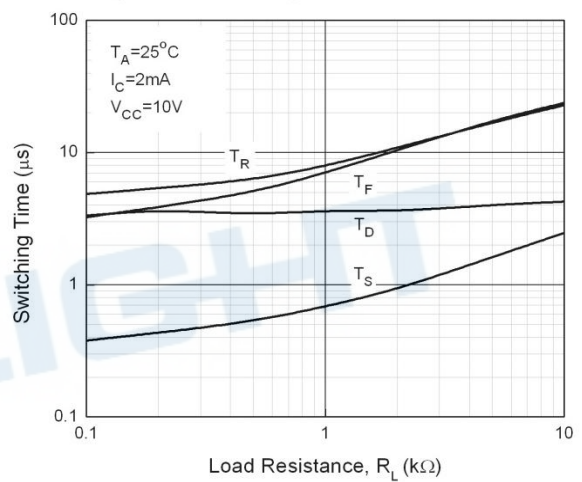


Figure 11. Switching Time Test Circuit & Waveforms

Order Information

Part Number

ELD3H7(Z)(DH)-VG
ELQ3H7(Z)(DH)-VG

Note

D3H7, Q3H7 = Part No.

Z = Tape and reel option (TA or none).

DH = Customer code

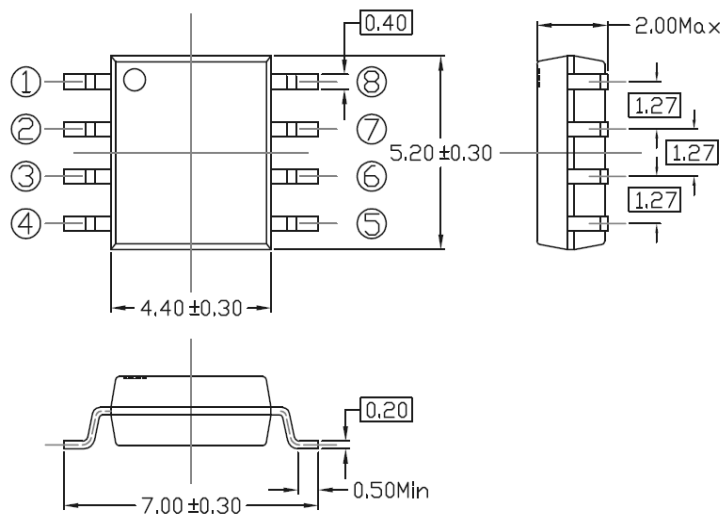
V = VDE (optional)

G = Halogens free

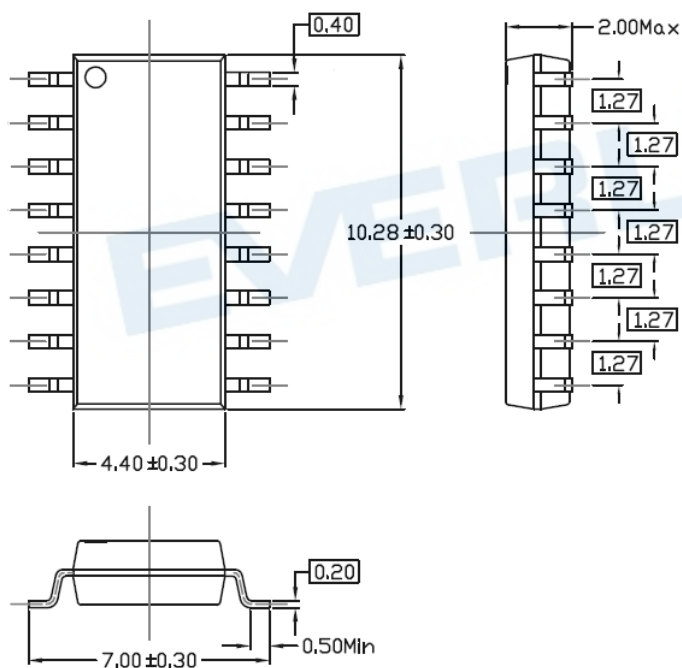
Option	Description	Packing quantity
None	Tube option of ELD3H7	80 units per tube
(TA)	Tape & reel option of ELD3H7	1000 units per reel
None	Tube option of ELQ3H7	40 units per tube
(TA)	Tape & reel option of ELQ3H7	1000 units per reel

Package Dimension (Dimensions in mm)

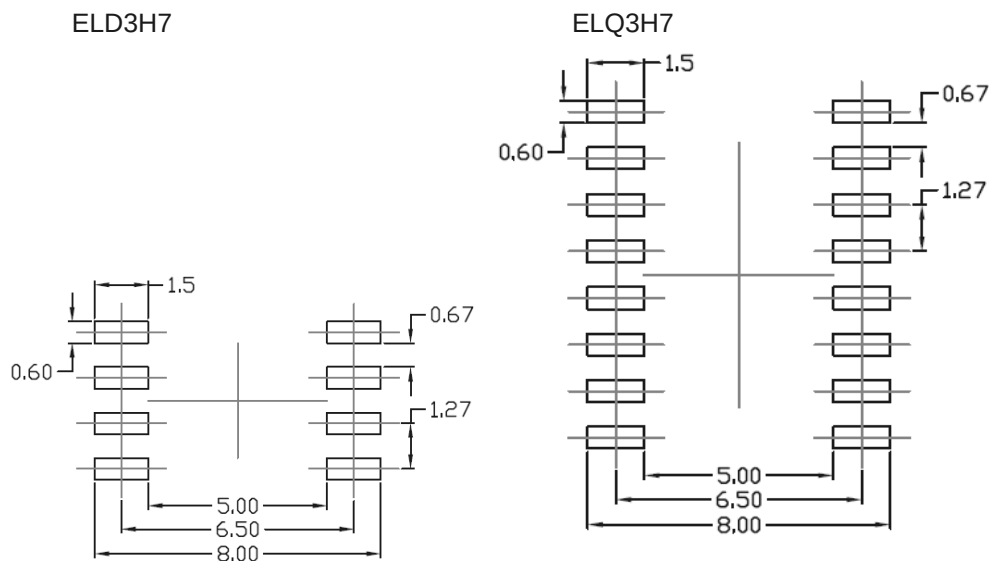
ELD3H7



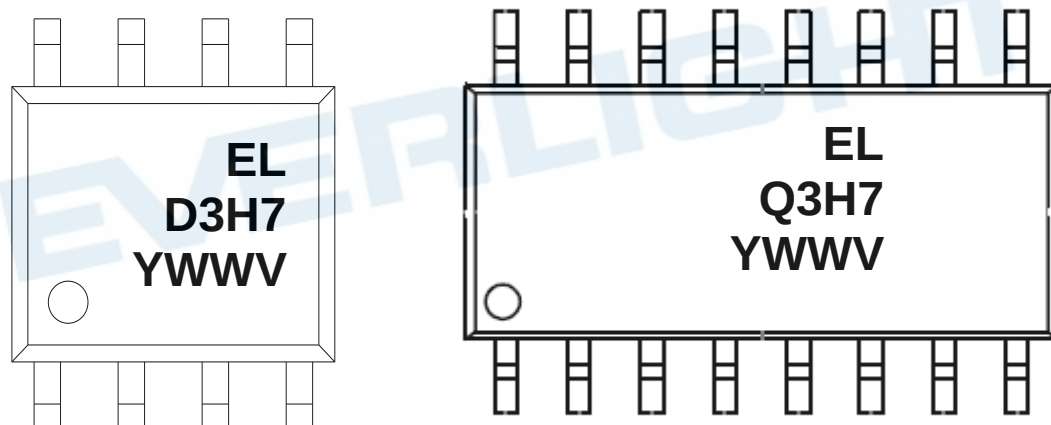
ELQ3H7



Recommended pad layout for surface mount leadform



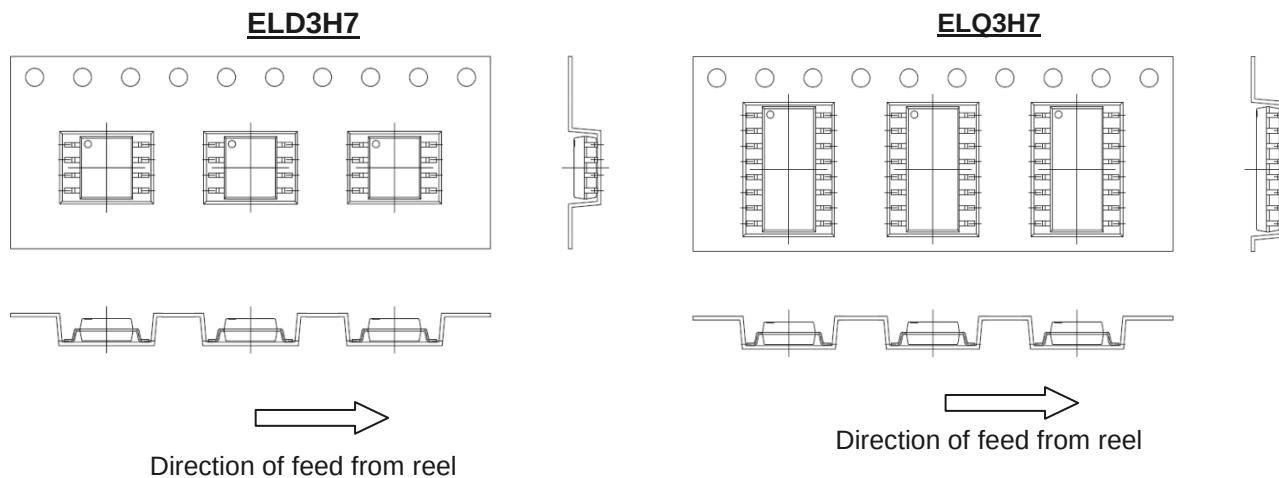
Device Marking



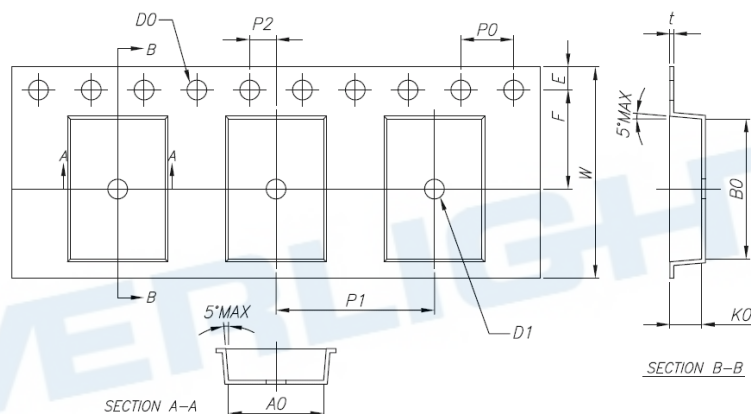
Notes

EL	denotes Everlight
Q3H7 D3H7	denotes Device Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

Tape & Reel Packing Specifications



Tape dimensions

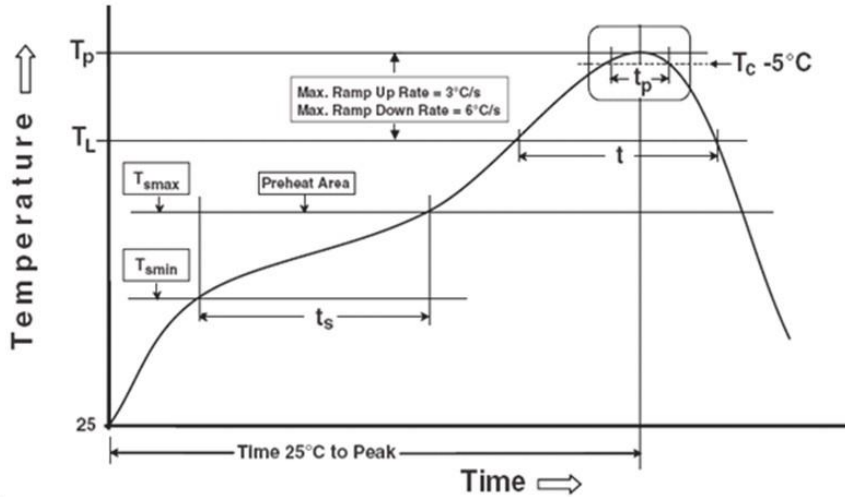


Dimension No.		A0	B0	D0	D1	E	F
Dimension (mm)	D3H7	7.4±0.1	5.6±0.1	1.5+0.1 -0	1.5+0.1 -0	1.75±0.1	7.5±0.1
	Q3H7	7.2±0.1	10.6±0.1	1.5+0.1 -0	1.5+0.1 -0	1.75±0.1	7.5±0.1
Dimension No.		P0	P1	P2	t	W	K0
Dimension (mm)	D3H7	4.0±0.1	12.0±0.1	2.0±0.1	0.3±0.05	16.0±0.3	2.4±0.1
	Q3H7	4.0±0.1	12.0±0.1	2.0±0.1	0.3±0.05	16.0±0.3	2.4±0.1

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin})

150 °C

Temperature max (T_{smax})

200°C

Time (T_{smin} to T_{smax}) (t_s)

60-120 seconds

Average ramp-up rate (T_{smax} to T_p)

3 °C/second max

Other

Liquidus Temperature (T_L)

217 °C

Time above Liquidus Temperature (t_L)

60-100 sec

Peak Temperature (T_p)

260°C

Time within 5 °C of Actual Peak Temperature: $T_p - 5^\circ C$

30 s

Ramp- Down Rate from Peak Temperature

6°C /second max.

Time 25°C to peak temperature

8 minutes max.

Reflow times

3 times

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